e2V e2V technologies

N6315 Series | Stellar 150 W TWT, 13.75 - 14.5 GHz Antenna Mount TWTA



- Fully Weatherproof Allows exposed mounting in mobile applications.
- Ruggedised Designed specifically for use in antenna mount applications.
- Lightweight Weighs less than 12 kg.
- **EMC** Complies with current worldwide specifications.
- Power Factor Correction Broad input voltage range allows connection to portable or mains supplies worldwide.
- Reliable Designed and built to provide a high level of reliability in all applications, from fixed ground base to flyaway systems.
- Digital Operation Designed for digital and analogue satellite communications, meeting the requirements of Intelsat and Eutelsat uplink specifications.
- Redundant Control Contains all the necessary control and drive requirements to implement a basic waveguide switch based redundant system.
- Stand Alone Setting A selectable facility that automatically sequences the unit to the transmit mode, upon application of the mains power. This reduces the complexity of control requirements for 'blackbox' applications.
- RF Circuit Includes RF input isolation RF output isolation, receiver rejection filter and harmonic filter as standard.

The amplifiers can be simply deployed anywhere in the world, are user friendly, and incorporate a comprehensive remote control facility as standard, including RS485.

TYPICAL DATA

Frequency								13.75 to 14.5	GHz
Output power	r a	t ou	ıtp	ut '	flar	nge			
(see note)								150	W
Gain at rated	ро	wei	r					65	dB
Prime power								99 to 265 V	nom
								47 to 63	Hz
								900	VA
Power factor								0.99	nom
Dimensions								436 mm (17.2 inches)	long
								213 mm (8.4 inches) v	wide
								203 mm (8.0 inches)	high
Weight								11.5	kg

Note Measured output power at the output flange will vary depending on operating frequency, configuration of the measurement system and temperature, and will typically be between 135 and 150 W.

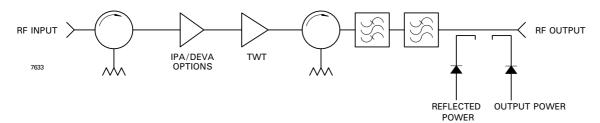
Variants

In addition to the N6315, variants are available which include a choice of options. These are shown on page 4, along with other accessories available from e2v technologies.

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INTERNAL SCHEMATIC



TEST PERFORMANCE

Frequency				13.75 to 14.5 GHz 135 W min ±0.3 dB max
Gain:	•	·	•	<u>.</u> 0.0 abax
at rated power				61 dB min
at P _{SAT} — 10 dB				66 dB min
stability (constant level,				
temperature and load)				± 0.25 dB max
stability over full operating				
temperature range				\pm 1.5 dB max
variation (ssg)				\pm 0.5 dB/80 MHz
slope (over any 50 MHz)				\pm 0.05 dB/MHz max
RF input level				+ 10 dBm max
Input VSWR (non-operating) .				. 1.5:1 max
Load VSWR:				
operate				. 1.5:1 max
no damage				. 2.0:1 max
Residual AM:				
<10 kHz				-40 dBc
10 to 500 kHz				$-20 (1 + \log f) dBc$
>500 kHz				-77 dBc
Noise and spurious:				
10.7 - 12.75 GHz				-150 dBW/4 kHz
13.75 - 14.5 GHz				−65 dBW/4 kHz
18 - 40 GHz				-100 dBW/4 kHz
Intermodulation: two equal carrie	ers,	tot	al	
power -7 dB of rated power				
Group delay (in any 50 MHz) .				. 1.0 ns p-p max
Phase noise				. Intelsat IESS-308
Harmonic output				−60 dBc max
AM to PM conversion (at rated p	ow	/er)		. 6 °/dB

ELECTRICAL

Prime power .		sin	igle	ph	nas	se, li	ne-neutral	or line-line
Voltage						99 t	o 265	V
Frequency						47	to 63	Hz
Power requirement							1050	VA max
Power factor .							. 0.95	min

MECHANICAL

Weight .							1	12.0 kg	(26 lb) max
Dimensions	S								see outline
Cooling .								integr	al forced-air

CONNECTORS

interface are supplied.

Note Mating	connectors	for the mains	supply and control
RF output .			WG17/WR75
RF input			type N female

ENVIRONMENTAL

For operation outside these parameters, refer to e2v technologies for guidance.
Operating temperature $-40 \text{ to } +45 ^{\circ}\text{C}$
Derating 2 °C/300 m above sea level
(3.6 °F/1000 ft)
Storage temperature -40 to $+80$ $^{\circ}$ C
Relative humidity (condensing) 100 %
Altitude:
operating 4.5 km (15,000 ft) max
non-operating
Vibration MIL-STD-810E;
common carrier and field transportation
Shock IEC Publication 68-2-27 Part 2 Test Ea
25 g
Electromagnetic compatibility . EMC Directive 89/336/EEC
Safety Low Voltage Directive 73/23/EEC
BS EN 60950

CONTROLS

All controls are achieved through the control interface connector, the functions are listed below:

Control inputs;

OFF

STANDBY

TRANSMIT

RF INHIBIT NO/NC

INTERLOCK

Indicator outputs;

OFF

WARMUP

STANDBY

TRANSMIT

FAULT SUMMARY

FOUR MULTIPLEXED FAULT LINES

Helix Current monitor

Output power monitor

RS-485 Serial Communications Port

(including address selection)

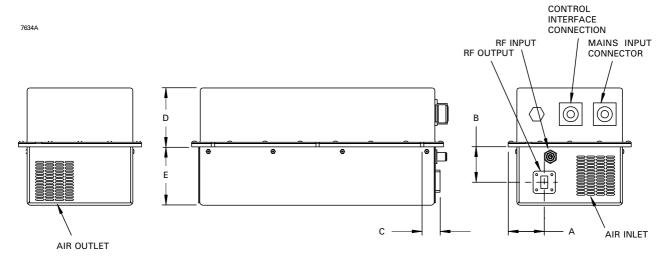
Auxiliary voltage output

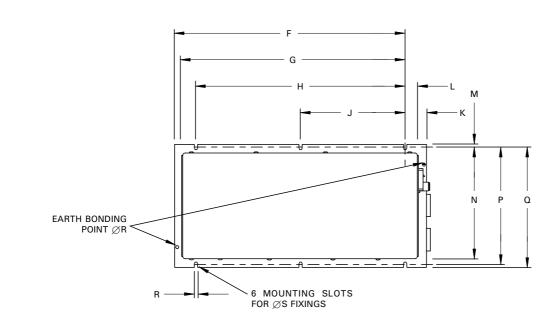
Redundant system control and waveguide switch drive

'Stand alone' setting for automatic power-up.

OUTLINE

(All dimensions without limits are nominal)





Ref	Millimetres	Inches
A	61 ± 1	2.40 ± 0.04
В	59 ± 1	2.34 ± 0.04
С	31 <u>+</u> 1	1.22 ± 0.04
D	102	4.02
E	101	3.98
F	399	15.71
G	387	15.24
Н	362	14.25
J	181	7.13
K	37	1.46
L	23	0.91
M	7	0.28
Ν	192	7.56
Р	200	7.87
Q	207	8.15
R	6	0.22
S	5	0.20

Inch dimensions have been derived from millimetres.

HEALTH AND SAFETY HAZARDS

e2v technologies electronic devices are safe to handle and operate provided that the relevant precautions are observed. e2v technologies does not accept responsibility for damage or injury resulting from the use of electronic devices it produces.



High Voltage

Dangerous voltages are present within the TWT amplifier when operating normally. However, the equipment is designed so that personnel cannot come into contact with high voltage circuits unless covers are removed.



RF Radiation

All RF connectors must be correctly fitted before operation.



Beryllia

The TWT in the amplifier contains beryllium oxide ceramic parts. These are not accessible unless the TWT casing is damaged. Consult e2v technologies regarding the disposal of damaged or life-expired tubes.

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N63xx SERIES OPTIONS

In addition to the standard product, the following variants and options are available. Contact e2v technologies for further information. To order an option please add the suffix letter to the HPA part number, for example to order a 180W HPA with built-in upconverter and digital gain control with a sample port would be part number **N6318DUAP**.

DEVA OPTION (D)

A digital electronically variable attenuator (DEVA) that provides a typical gain adjustment of 30 dB with a control resolution of 0.125 dB, controlled via the RS485 serial communications control link.

Gain:

at rated power				62	dB typ.
				58	dB min.
at $P_{SAT} - 10 dB$				63	dB min.
Adjustment				30	dB typ.
				20	dB min.

SAMPLE PORT (P)

The RF Sample port is situated on the end panel (opposite end to mains input connections).

RF sample						50	dB nom.
Connector							N-type female

INTEGRAL UPCONVERTERS (UA) or (UB)

It is recommended that the DEVA option is used if an integral upconverter is required (DUA or DUB). If the DEVA option is not included with the upconverter, then the external 10 MHz reference signal to the amplifier should be disabled.

Two versions of L-band to Ku-band upconverter, a 500 MHz and a 750 MHz version, that are fitted within the antenna mount amplifier package.

Input frequency:

14.00 to 14.50 GHz (UA version) 950 to 1	1450 MHz
13.75 to 14.50 GHz (UB version) 950 to 1	1700 MHz
Gain:	
at rated output 50	dB typ.
47	dB min.
at $P_{SAT} - 10 \text{ dB}$ 56	dB typ.
53	dB min.
L-band input level -10	dBm min.
0	dBm max.
Input VSWR 2.0:1	max.
External reference input on incoming RF:	
frequency 10	MHz
level	dBm min.
0	dBm max.

UPCONVERTER BREAK-OUT LINK (S)

Allows access to the Ku-band TWT drive signal when an integral upconverter is fitted. Typically used for monitoring, setup, redundant switching or bypass configuration. The link is situated on the end panel (opposite end to mains input connections).

Connectors SMA-type female

LOW GAIN OPTION (C)

The internal solid-state pre-amplification stage of the standard amplifier is omitted.

Gain:

at rated power .					36	dB typ.
					33	dB min.
at $P_{SAT} - 10 dB$					38	dB min.
RF input level					+ 30	dBm max.

Note Not available with the upconverter option.

STELLAR ACCESSORIES

This product is supplied with an Operation Manual, a mains connector mating half, a control connector mating half and an air cowl.

Additional accessories available from e2v technologies include:

- N6143 ODU 1:1 Control Unit housed in a standard 19inch rack mountable, 1U high enclosure. The N6143
 provides the user with full remote control of two amplifiers
 and a redundant switch. It can be used to control a single
 amplifier, allowing for future expansion, including
 redundancy.
- DPP563119BA Circular Duct Adaptor can be fitted to either the cooling air inlet or outlet and provides a method of connecting to a solid wall or flexible duct.
- DAS563573AA Waveguide Window Kit provides a method of sealing the internal waveguide system, preventing moisture ingress from the external waveguide system, and reducing the risk of subsequent amplifier damage. The window is designed to fit between the RF output flange and the external waveguide system flange. The window is approximately 6 mm long, increasing outline dimension C to 37 ± 1 mm. The kit comprises the waveguide window, longer fixing screws and an O-ring seal.
- DPP563119AA Additional air cowls
- DAS563750AA Additional mains connector mating parts
- DAS563751AA Additional control connector mating parts

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